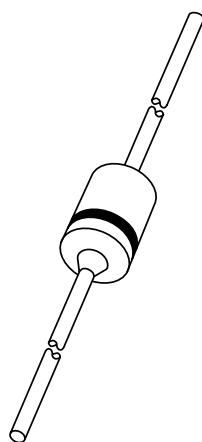


DATA SHEET



BAS11; BAS12 Controlled avalanche rectifiers

Product specification
Supersedes data of April 1996

1996 Sep 26

Controlled avalanche rectifiers

BAS11; BAS12

FEATURES

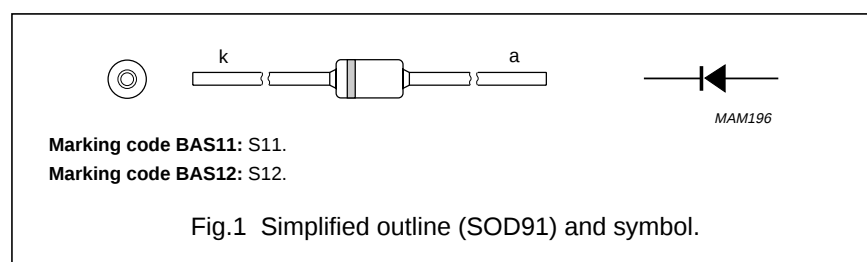
- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Available in ammo-pack.

DESCRIPTION

Rectifier diodes in cavity free cylindrical SOD91 glass packages, incorporating Implotech™⁽¹⁾ technology.

(1) Implotech is a trademark of Philips.

These packages are hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage BAS11 BAS12		–	300	V
			–	400	V
V_{RWM}	working reverse voltage BAS11 BAS12		–	300	V
			–	400	V
V_R	continuous reverse voltage BAS11 BAS12		–	300	V
			–	400	V
$I_{F(AV)}$	average forward current	averaged over any 20 ms period; $T_{tp} = 75\text{ °C}$; lead length = 10 mm; see Figs 2 and 4	–	350	mA
		averaged over any 20 ms period; $T_{amb} = 30\text{ °C}$; PCB mounting (see Fig.8); see Figs 3 and 4	–	300	mA
I_{FSM}	non-repetitive peak forward current	$t = 10\text{ ms}$ half sinewave; $T_j = T_{j\max}$ prior to surge; $V_R = V_{RRM\max}$	–	4	A
P_{RRM}	repetitive peak reverse power dissipation	$t = 10\text{ }\mu\text{s}$ square wave; $f = 50\text{ Hz}$; $T_{amb} = 25\text{ °C}$	–	75	W
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–65	+150	°C

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ELECTRICAL CHARACTERISTICS $T_j = 25\text{ }^{\circ}\text{C}$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	$I_F = 300\text{ mA}$; $T_j = T_{j\text{max}}$; see Fig.5	–	–	1.0	V
		$I_F = 300\text{ mA}$; see Fig.5	–	–	1.1	V
$V_{(BR)R}$	reverse avalanche breakdown voltage BAS11 BAS12	$I_R = 0.1\text{ mA}$	330	–	–	V
			440	–	–	V
I_R	reverse current	$V_R = V_{RRM\text{max}}$; see Fig.6	–	–	250	nA
		$V_R = V_{RRM\text{max}}$; $T_j = 125\text{ }^{\circ}\text{C}$; see Fig.6	–	–	10	μA
t_{rr}	reverse recovery time	when switched from $I_F = 0.5\text{ A}$ to $I_R = 1\text{ A}$; measured at $I_R = 0.25\text{ A}$; see Fig.9	–	–	1	μs
C_d	diode capacitance	$V_R = 0\text{ V}$; $f = 1\text{ MHz}$; see Fig.7	–	20	–	pF

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length = 10 mm	180	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	340	K/W

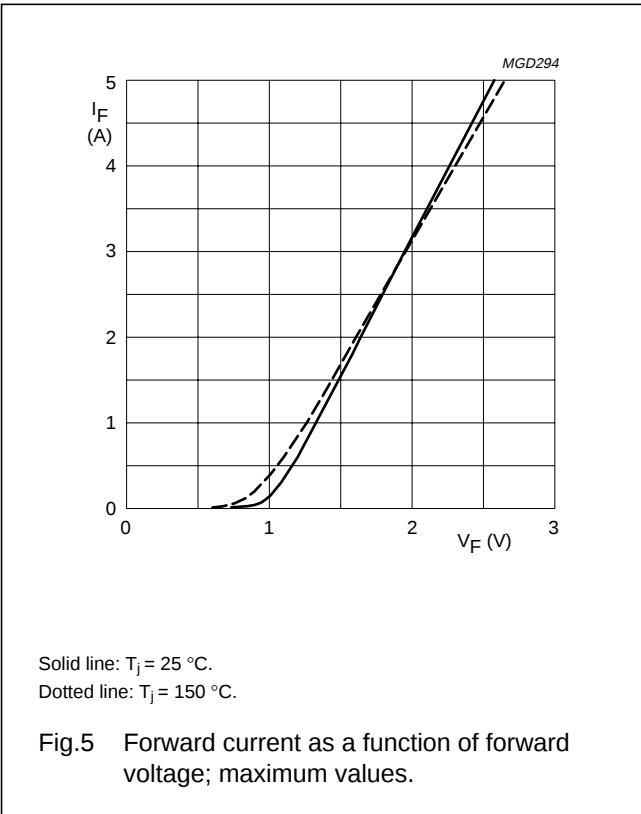
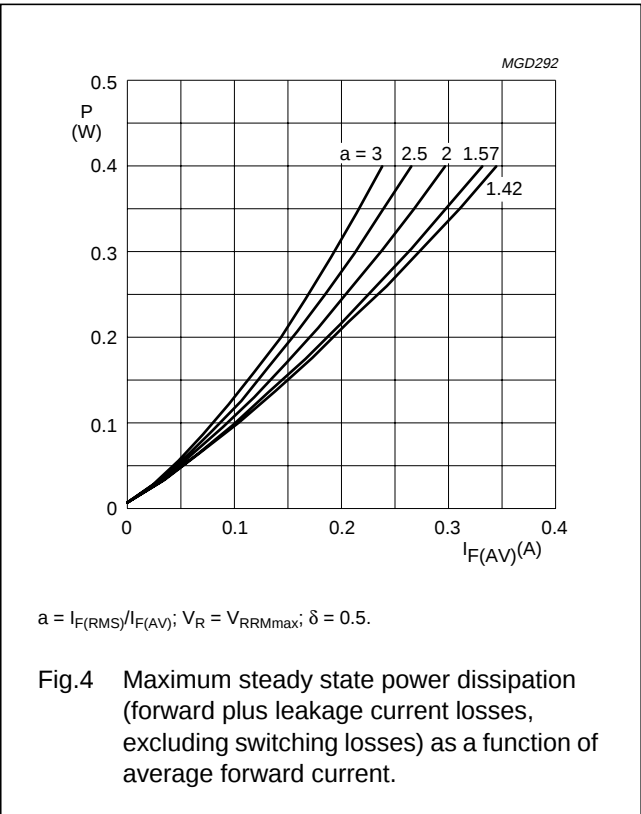
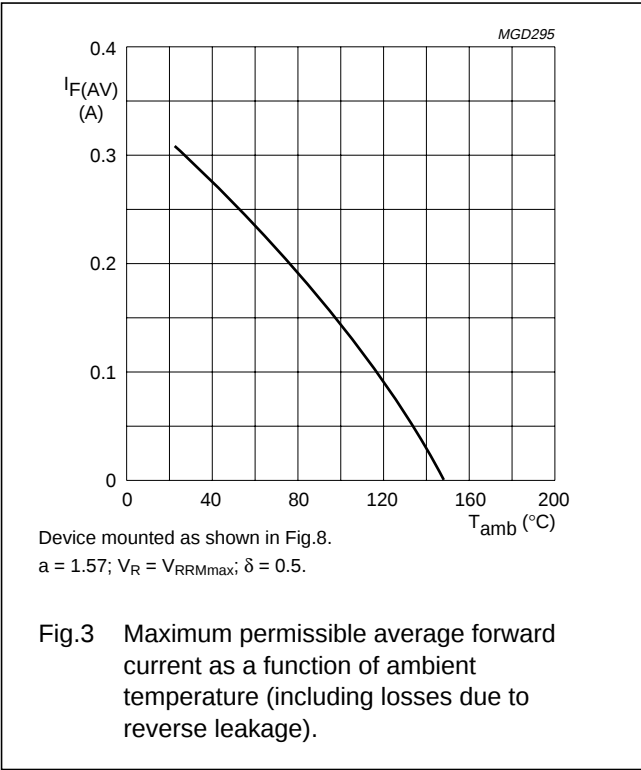
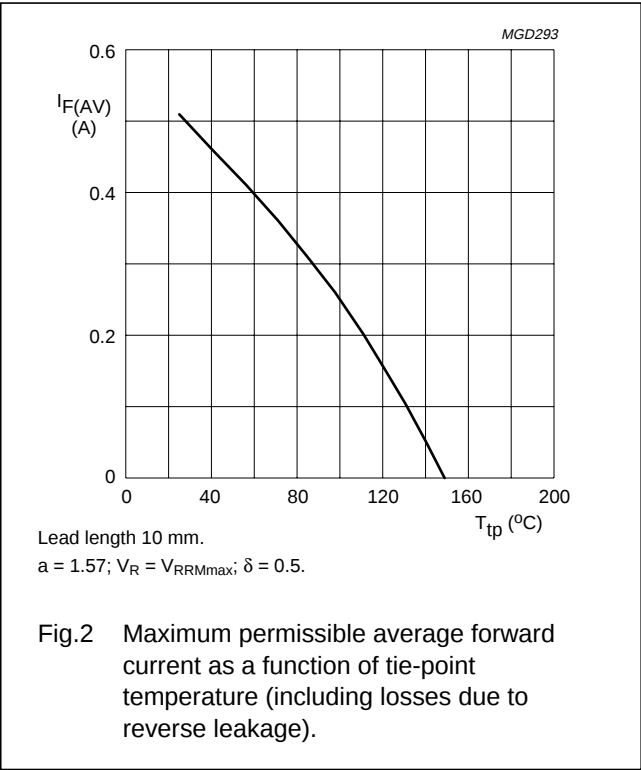
Note

1. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper $\geq 40\text{ }\mu\text{m}$, see Fig.8.
For more information please refer to the "General Part of associated Handbook".

Controlled avalanche rectifiers

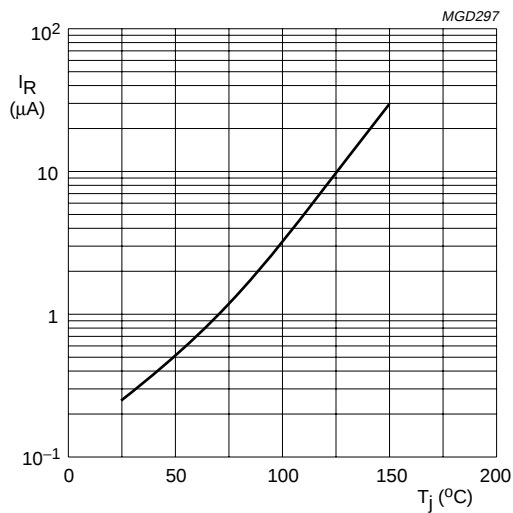
BAS11; BAS12

GRAPHICAL DATA



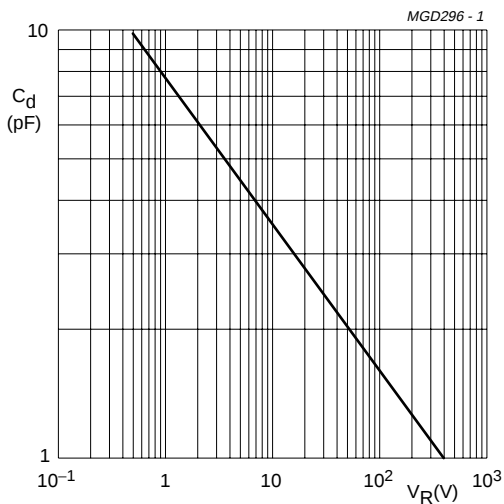
Controlled avalanche rectifiers

BAS11; BAS12



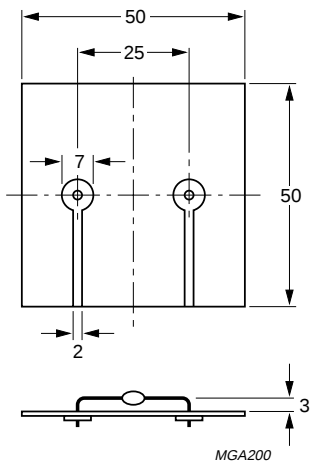
$V_R = V_{RRMmax}$.

Fig.6 Reverse current as a function of junction temperature; maximum values.



$f = 1\text{ MHz}; T_j = 25\text{ }^{\circ}C$.

Fig.7 Diode capacitance as a function of reverse voltage; typical values.

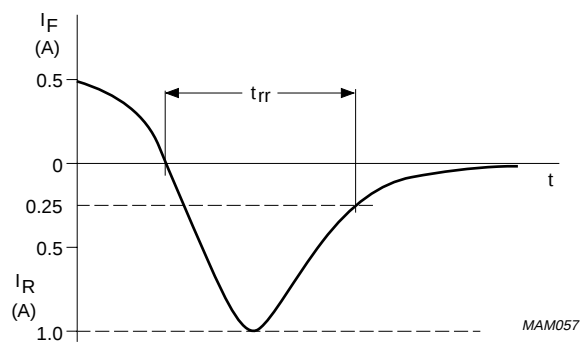
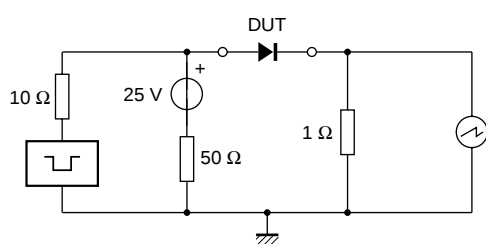


Dimensions in mm.

Fig.8 Device mounted on a printed-circuit board.

Controlled avalanche rectifiers

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Input impedance oscilloscope: $1\text{ M}\Omega$, 22 pF ; $t_r \leq 7\text{ ns}$.

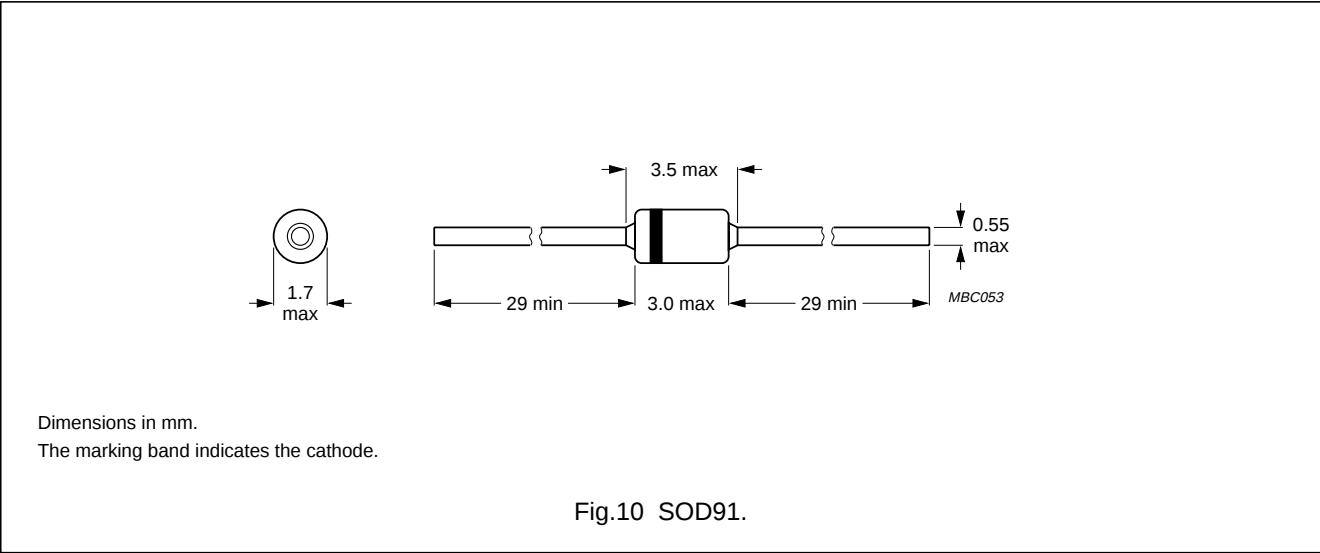
Source impedance: $50\text{ }\Omega$; $t_r \leq 15\text{ ns}$.

Fig.9 Test circuit and reverse recovery time waveform and definition.

Controlled avalanche rectifiers

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PACKAGE OUTLINE



DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.